

## Features

- $BV_{CEO} > -100V$
- $I_C = -5A$  High Continuous Collector Current
- $I_{CM} = -10A$  Peak Pulse Current
- Low Saturation Voltage  $V_{CE(sat)} < -115mV @ -1A$
- $R_{CE(sat)} = 75m\Omega$  for a Low Equivalent On-Resistance
- $h_{FE}$  Specified up to  $-10A$  for a High Gain Hold-up
- Complementary NPN Type: DIODES™ FZT853
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **An Automotive-Compliant Part is Available Under Separate Datasheet (FZT953Q)**

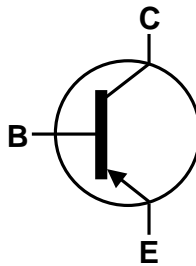
## Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.112 grams (Approximate)

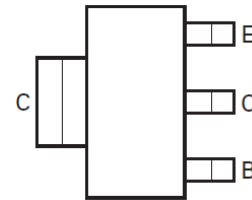
SOT223 (Type DN)



Top View



Device Symbol



Top View  
Pin-Out

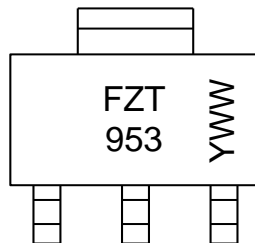
## Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
FZT953TA	SOT223 (Type DN)	FZT953	7	12	1,000	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information

SOT223 (Type DN)



FZT953 = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 2 = 2022)  
 WW or  $\bar{W}W$  = Week Code (01 to 53)

### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB0</sub>	-140	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-100	V
Emitter-Base Voltage	V <sub>EB0</sub>	-7	V
Continuous Collector Current	I <sub>C</sub>	-5	A
Peak Pulse Current	I <sub>CM</sub>	-10	A

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

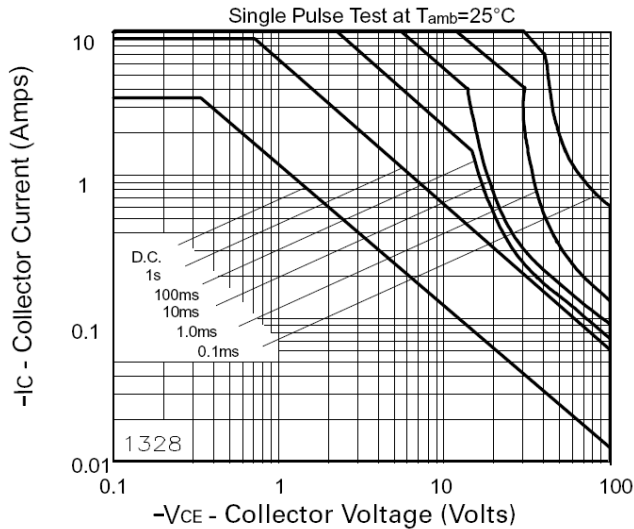
Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P <sub>D</sub>	3.0	W
		24	
		1.6	mW/°C
		12.8	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	42	°C/W
	R <sub>θJA</sub>	78	
Thermal Resistance, Junction to Lead	R <sub>θJL</sub>	8.84	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

### ESD Ratings (Note 8)

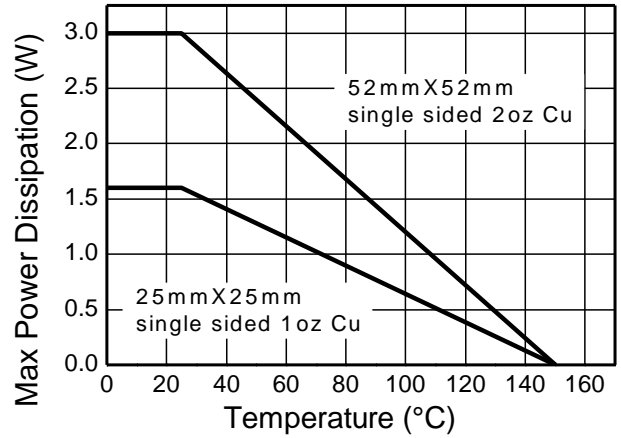
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

- Notes:
5. For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
  6. Same as Note 5, except the device is surface mounted on 25mm x 25mm with 1oz copper.
  7. Thermal resistance from junction to solder-point (at the end of the collector lead).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

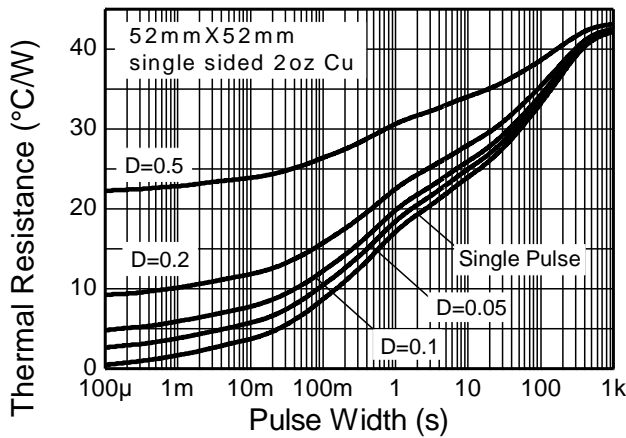
**Thermal Characteristics and Derating Information**



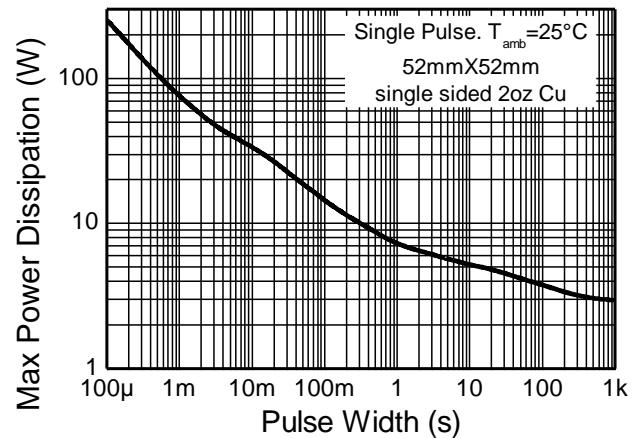
**Figure 1. Safe Operating Area**



**Figure 2. Derating Curve**



**Figure 3. Transient Thermal Impedance**



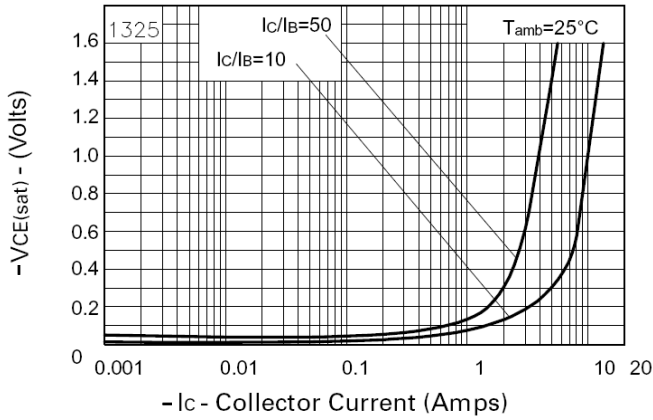
**Figure 4. Pulse Power Dissipation**

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

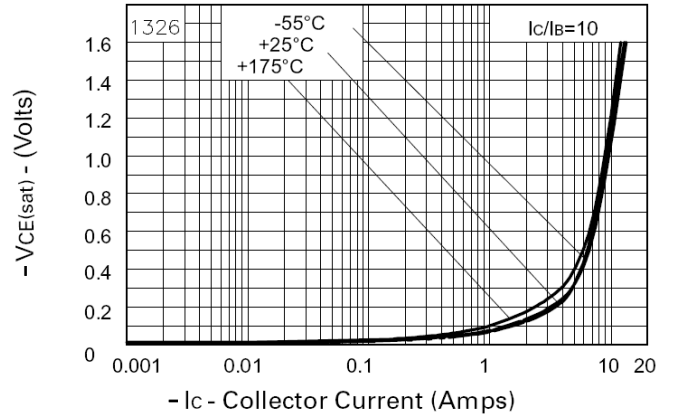
Characteristic	Symbol	Min	Typ.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CB0</sub>	-140	-170	—	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CER</sub>	-140	-170	—	V	I <sub>C</sub> = -1μA, R <sub>B</sub> ≤ 1kΩ
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-100	-120	—	V	I <sub>C</sub> = -1mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8	—	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CB0</sub>	—	<-1	-50	nA	V <sub>CB</sub> = -100V
		—	—	-1	μA	V <sub>CB</sub> = -100V, T <sub>A</sub> = +100°C
Collector Cutoff Current	I <sub>CER</sub>	—	<-1	-50	nA	V <sub>CE</sub> = -100V, R ≤ 1kΩ
		—	—	-1	μA	V <sub>CE</sub> = -100V, T <sub>A</sub> = +100°C
Emitter Cutoff Current	I <sub>EBO</sub>	—	<-1	-10	nA	V <sub>EB</sub> = -6V
DC Current Transfer Static Ratio (Note 9)	h <sub>FE</sub>	100	200	—	—	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -1V
		100	200	300		I <sub>C</sub> = -1A, V <sub>CE</sub> = -1V
		50	90	—		I <sub>C</sub> = -3A, V <sub>CE</sub> = -1V
		30	50	—		I <sub>C</sub> = -4A, V <sub>CE</sub> = -1V
		—	15	—		I <sub>C</sub> = -10A, V <sub>CE</sub> = -1V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	—	-20	-50	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA
		—	-90	-115		I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
		—	-160	-220		I <sub>C</sub> = -2A, I <sub>B</sub> = -200mA
		—	-300	-420		I <sub>C</sub> = -4A, I <sub>B</sub> = -400mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	—	-1,010	-1,170	mV	I <sub>C</sub> = -4A, I <sub>B</sub> = -400mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	—	-925	-1,160	mV	I <sub>C</sub> = -4A, V <sub>CE</sub> = -1V
Transitional Frequency	f <sub>T</sub>	—	125	—	MHz	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V f = 50MHz
Output Capacitance	C <sub>obo</sub>	—	65	—	pF	V <sub>CB</sub> = -10V, f = 1MHz
Switching Time	t <sub>on</sub>	—	110	—	ns	V <sub>CC</sub> = -10V, I <sub>C</sub> = -2A I <sub>B1</sub> = -I <sub>B2</sub> = -200mA
	t <sub>off</sub>	—	460	—		

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

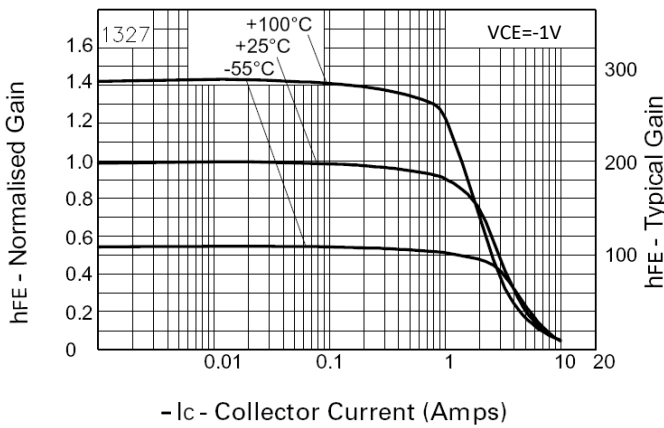
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



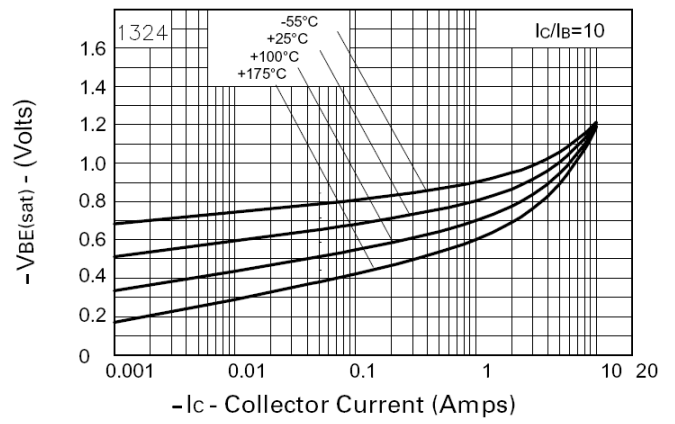
**Figure 5.  $V_{CE(sat)}$  v  $I_c$**



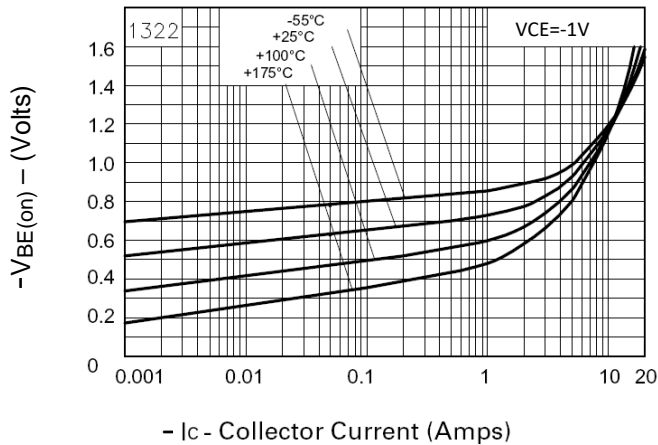
**Figure 6.  $V_{CE(sat)}$  v  $I_c$**



**Figure 7.  $h_{FE}$  v  $I_c$**



**Figure 8.  $V_{BE(sat)}$  v  $I_c$**

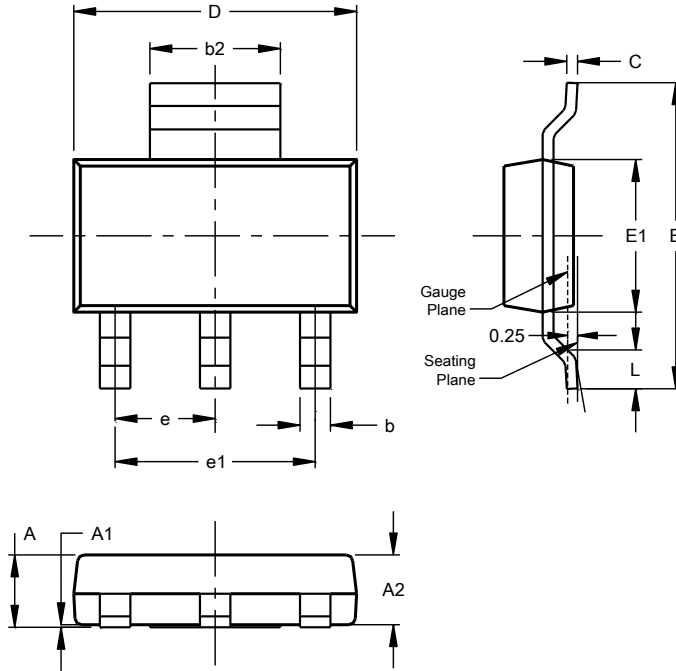


**Figure 9.  $V_{BE(on)}$  v  $I_c$**

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)

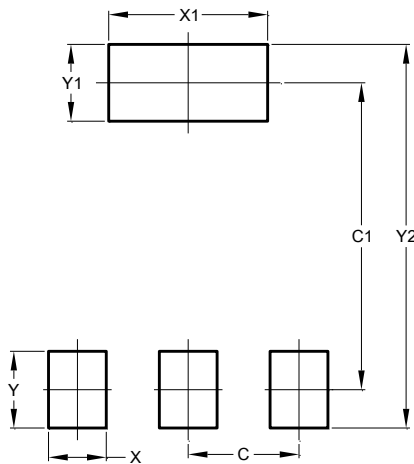


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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